


### Publisher Correction: A high-frequency artificial nerve based on homogeneously integrated organic electrochemical transistors

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 Check for updates

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In the version of the article initially published, the scale bar label in Fig. 3h, now reading “5 mm”, appeared incorrectly in the original version (as “5 nm”), and the last sentence in the second paragraph of the “sv-OECTs based on GIBS” section, now reading “Moreover,  $g_m/\tau = 519 \text{ S s}^{-1}$ ...”, originally appeared as “Moreover,  $g_m/\tau = 519 \text{ mS s}^{-1}$ ...”. The errors have been corrected in the HTML and PDF versions of the article.

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